# 6-Channel Differential 1:2 Switch for PCIe 3.0 and DisplayPort 1.2

The NCN3612B is a 6–Channel differential SPDT switch designed to route PCI Express Gen3 and/or DisplayPort 1.2 signals. Due to the ultra–low ON–state capacitance (2.1 pF typ) and resistance (8  $\Omega$  typ), this switch is ideal for switching high frequency signals up to a signal bit rate (BR) of 8 Gbps. This switch pinout is designed to be used in BTX form factor desktop PCs and is available in a space–saving 5x11x0.75 mm WQFN56 package. The NCN3612B uses 80% less quiescent power than other comparable PCIe switches.

#### Features

- BTX Pinout
- V<sub>DD</sub> Power Supply from 3 V to 3.6 V
- Low Supply Current: 250 µA typ
- 6 Differential Channels, 2:1 MUX/DEMUX
- Compatible with Display Port 1.2 & PCIe 3.0
- Data Rate: Supports 8 Gbps
- Low  $R_{ON}$  Resistance: 8  $\Omega$  typ
- Low C<sub>ON</sub> Capacitance: 2.1 pF
- Space Saving, Small WQFN-56 Package
- This is a Pb–Free Device

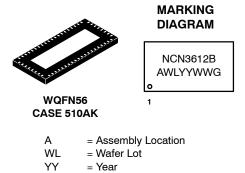
#### **Typical Applications**

- Notebook Computers
- Desktop Computers
- Server/Storage Networks



# **ON Semiconductor®**

#### http://onsemi.com



WW = Work Week

G

= Pb-Free Package

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NCN3612BMTTWG	WQFN56 (Pb–Free)	2000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

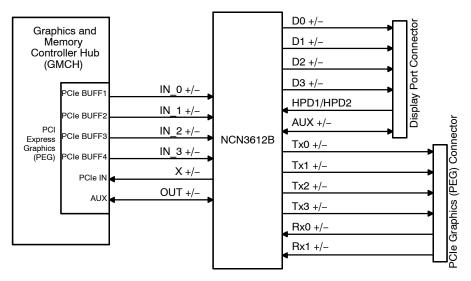
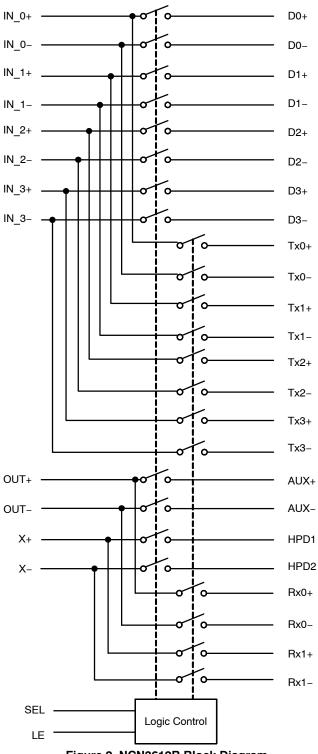


Figure 1. Application Schematic



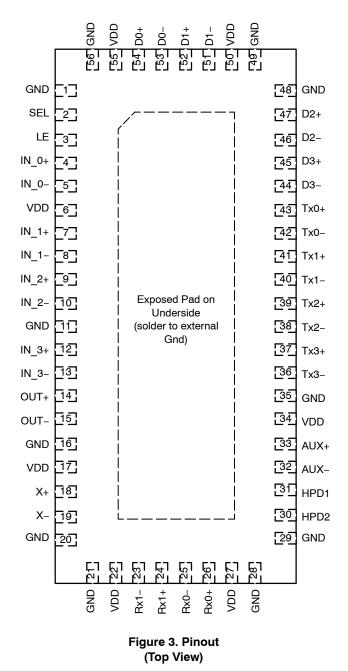


### **TRUTH TABLE (SEL Control)**

Function	SEL
PCI Express Gen3 Path is Active (Tx, Rx)	L
Digital Video Port is Active (D, HPD, AUX)	Н

### **TRUTH TABLE (Latch Control)**

LE	Internal Mux Select	
L	Respond to Changes on SEL	
Н	Latched	



### PIN FUNCTION AND DESCRIPTION

Pin	Name	Description
6, 17, 22, 27, 34,50, 55	VDD	DC Supply, 3.3 V $\pm$ 10%
1, 11, 16, 20, 21, 28, 29, 35, 48, 49, 56	GND	Power Ground.
Exposed Pad	_	The exposed pad on the backside of package is internally connected to Gnd. Externally the exposed pad should also be user-connected to GND.
2	SEL	SEL controls the mux through a flow-through latch. Do not float this pin. SEL = 0 for PCIE Mode; SEL = 1 for DP Mode
3	LE	LE controls the latch gate. Do not float this pin.
4	IN_0+	Differential input from GMCH PCIE outputs. IN_0+ makes a differential pair with IN_0
5	IN_0-	Differential input from GMCH PCIE outputs. IN_0- makes a differential pair with IN_0+.
7	IN_1+	Differential input from GMCH PCIE outputs. IN_1+ makes a differential pair with IN_1
8	IN_1-	Differential input from GMCH PCIE outputs. IN_1- makes a differential pair with IN_1+.
9	IN_2+	Differential input from GMCH PCIE outputs. IN_2+ makes a differential pair with IN_2
10	IN_2-	Differential input from GMCH PCIE outputs. IN_2- makes a differential pair with IN_2+.
12	IN_3+	Differential input from GMCH PCIE outputs. IN_3+ makes a differential pair with IN_3
13	IN_3-	Differential input from GMCH PCIE outputs. IN_3- makes a differential pair with IN_3+.
14	OUT+	Pass-through output from AUX+ input when SEL = 1. Pass-through output from Rx0+ input when SEL = 0.
15	OUT-	Pass-through output from AUX- input when SEL = 1. Pass-through output from Rx0- input when SEL = 0.
18	X+	X+ is an analog pass-through output corresponding to Rx1+.
19	X-	X- is an analog pass-through output corresponding to the Rx1- input. The path from Rx1- to X- must be matched with the path from Rx1+ to X+. X+ and X- form a differential pair when the pass-through mux mode is selected.
23	Rx1–	Differential input from PCIE connector or device. $Rx1-$ makes a differential pair with $Rx1+$ . $Rx1-$ is passed through to the X- pin on the path that matches the $Rx1+$ to X+ pin.
24	Rx1+	Differential input from PCIE connector or device. $Rx1+$ makes a differential pair with $Rx1-$ . $Rx1+$ is passed through to the X+ pin when SEL = 0.
25	Rx0-	Differential input from PCIE connector or device. Rx0- makes a differential pair with Rx0+. Rx0- is passed through to the OUT- pin when SEL = 0.
26	Rx0+	Differential input from PCIE connector or device. Rx0+ makes a differential pair with Rx0 Rx0+ is passed through to the OUT+ pin when SEL = 0.
30	HPD2	Negative low frequency HPD input handshake protocol signal (normally not connected).
31	HPD1	Positive low frequency HPD input handshake protocol signal.
32	AUX-	Differential input from HDMI/DP connector. AUX- makes a differential pair with AUX+. AUX- is passed through to the OUT- pin when SEL = 1.
33	AUX+	Differential input from HDMI/DP connector. AUX+ makes a differential pair with AUX AUX+ is passed through to the OUT+ pin when SEL = 1.
37, 36	Tx3+, Tx3-	Analog pass-through output#2 corresponding to IN_3+ and IN_3- when SEL = 0.
39, 38	Tx2+, Tx2-	Analog pass-through output#2 corresponding to IN_2+ and IN_2- when SEL = 0.
41, 40	Tx1+, Tx1-	Analog pass-through output#2 corresponding to IN_1+ and IN_1- when SEL = 0.
43, 42	Tx0+, Tx0-	Analog pass-through output#2 corresponding to IN_0+ and IN_0- when SEL = 0.
45, 44	D3+, D3-	Analog pass-through output#1 corresponding to IN_3+ and IN_3-, when SEL = 1.
47, 46	D2+, D2–	Analog pass-through output#1 corresponding to IN_2+ and IN_2-, when SEL = 1.
52, 51	D1+, D1–	Analog pass-through output#1 corresponding to IN_1+ and IN_1-, when SEL = 1.
54, 53	D0+, D0-	Analog pass-through output#1 corresponding to IN_0+ and IN_0-, when SEL = 1.

#### **MAXIMUM RATINGS**

Parameter	Symbol	Rating	Unit
Power Supply Voltage	V <sub>DD</sub>	-0.5 to 5.3	V <sub>DC</sub>
Input/Output Voltage Range of the Switch (Tx, Rx, D, HPD, AUX, IN_, OUT, X)	V <sub>IS</sub>	–0.5 to V <sub>DD</sub> + 0.3	V <sub>DC</sub>
Selection Pin Voltages (SEL and LE)	V <sub>IN</sub>	–0.5 to V <sub>DD</sub> + 0.3	V <sub>DC</sub>
Continuous Current Through One Switch Channel	I <sub>IS</sub>	±120	mA
Maximum Junction Temperature (Note 1)	Т <sub>Ј</sub>	150	°C
Operating Ambient Temperature	T <sub>A</sub>	-40 to +85	°C
Storage Temperature Range	T <sub>stg</sub>	-65 to +150	°C
Thermal Resistance, Junction-to-Air (Note 2)	$R_{ heta JA}$	37	°C/W
Latch-up Current (Note 3)	I <sub>LU</sub>	±100	mA
Human Body Model (HBM) ESD Rating (Note 4)	ESD HBM	7000	V
Machine Model (MM) ESD Rating (Note 4)	ESD MM	400	V
Moisture Sensitivity (Note 5)	MSL	Level 1	-

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

 Power dissipation must be considered to ensure maximum junction temperature (T<sub>J</sub>) is not exceeded.
This parameter is based on EIA/JEDEC 51–7 with a 4–layer PCB, 80 mm x 80 mm, two 1oz Cu material internal planes and top planes of 2oz Ċu material.

3. Latch up Current Maximum Rating: ±100 mA per JEDEC standard: JESD78.

- 4. This device series contains ESD protection and passes the following tests: Human Body Model (HBM) ±7.0 kV per JEDEC standard: JESD22–A114 for all pins. Machine Model (MM) ±400 V per JEDEC standard: JESD22–A115 for all pins.
- 5. Moisture Sensitivity Level (MSL): 1 per IPC/JEDEC standard: J-STD-020A.

**ELECTRICAL CHARACTERISTICS** ( $V_{DD}$  = +3.3V ±10%,  $T_A$  = -40°C to +85°C, unless otherwise noted. All Typical values are at  $V_{DD}$  = +3.3 V,  $T_A$  = +25°C, unless otherwise noted.)

Symbol	Characteristics	Conditions	Min	Тур	Max	Unit
POWER S	UPPLY	•	•			
V <sub>DD</sub>	Supply Voltage Range		3.0	3.3	3.6	V
I <sub>DD</sub>	Power Supply Current	$V_{DD}$ = 3.6 V, $V_{IN}$ = GND or $V_{DD}$		250	350	μA
DATA SW	TCH PERFORMANCE (for both PC	Cle and DisplayPort applications, unless otherwise r	noted)			
V <sub>IS</sub>	Data Input/Output Voltage Range		0		1.2	V
R <sub>ON</sub>	On Resistance (Tx, Rx)	$V_{DD} = 3 V$ , $V_{IS} = 0 V$ to 1.2 V, $I_{IS} = 15 mA$		8.0	13	Ω
R <sub>ON</sub>	On Resistance (D, HPD, AUX)	$V_{DD}$ = 3 V, $V_{IS}$ = 0 V to 1.2 V, $I_{IS}$ = 15 mA		9.0	13	Ω
R <sub>ON(flat)</sub>	On Resistance Flatness	$V_{DD}$ = 3 V, $V_{IS}$ = 0 V to 1.2 V, $I_{IS}$ = 15 mA (Note 6)		0.1	1.24	Ω
$\Delta R_{ON}$	On Resistance Matching (Tx, Rx)	$V_{DD}$ = 3 V, $V_{IS}$ = 0 V, $I_{IS}$ = 15 mA		0.35		Ω
$\Delta R_{ON}$	On Resistance Matching (D, HPD, AUX)	$V_{DD}$ = 3 V, $V_{IS}$ = 0 V, $I_{IS}$ = 15 mA		0.35		Ω
C <sub>ON</sub>	On Capacitance	f = 1 MHz, Switch On, Open Output		2.1		pF
C <sub>OFF</sub>	Off Capacitance	f = 1 MHz, Switch Off		1.6		pF
I <sub>ON</sub>	On Leakage Current (IN_/ X/OUT)	V <sub>DD</sub> = 3.6 V, V <sub>IN</sub> = Vx = V <sub>OUT</sub> = 0 V, 1.2 V; Switch On to D/HPD/AUX or Tx/Rx; outputs unconnected	-1		+1	μΑ
I <sub>OFF</sub>	Off Leakage Current (D/Tx/HPD/Rx/AUX)	$ \begin{array}{l} V_{DD} = 3.6 \text{ V}, V_{IN} = V_X = V_{OUT} = 0 \text{ V}, 1.2 \text{ V}; \\ \text{Switch Off; } V_D = V_{HPD} = V_{AUX} \text{ or } V_D = V_{HPD} = \\ V_{AUX} \text{ set to } 1.2 \text{ V}, 0 \text{ V} \end{array} $	-1		+1	μA
CONTROL	LOGIC CHARACTERISTICS (SE	L and LE pins)	-	-	-	
V <sub>IL</sub>	Off voltage input		0		0.8	V
VIH	High voltage input		2		V <sub>DD</sub>	V
I <sub>IN</sub>	Off voltage input	V <sub>IN</sub> = 0 V or V <sub>DD</sub>	-1		+1	μA
C <sub>IN</sub>	High voltage input	f = 1 MHz		1		pF
DYNAMIC	CHARACTERISTICS	·		-		
BR	Signal Data Rate			8		Gbp
D <sub>IL</sub>	Differential Insertion Loss	f = 100 MHz		-0.7		dB
		f = 2.7 GHz		-1.3		
		f = 4 GHz		-2		
D <sub>ISO</sub>	Differential Off Isolation	f = 100 MHz		-54		dB
		f = 2.7 GHz		-23		
		f = 4 GHz		-18		
D <sub>CTK</sub>	Differential Crosstalk	f = 100 MHz		-50		dB
		f = 2.7 GHz		-32		
		f = 4 GHz		-30		
D <sub>RL</sub>	Differential Return Loss	f = 100 MHz		-20		dB
		f = 3.7 GHz		-10		1

6. Guaranteed by characterization and/or design.

f = 4 GHz

-5

# SWITCHING CHARACTERISTICS (V\_DD = +3.3 V, T\_A = 25 $^{\circ}$ C, unless otherwise specified)

Symbol	Characteristics	Conditions	Min	Тур	Max	Unit
t <sub>b-b</sub>	Bit-to-bit skew	Within the same differential pair		7		ps
t <sub>ch-ch</sub>	Channel-to-channel skew	Maximum skew between all channels		55		ps

# SELECTION PINS SWITCHING CHARACTERISTICS (V<sub>DD</sub> = +3.3 V, T<sub>A</sub> = $25^{\circ}$ C, unless otherwise specified)

Symbol	Characteristics	Conditions	Min	Тур	Max	Unit
T <sub>SELON</sub>	SEL to Switch turn ON time	$V_{\text{IS}}$ = 1 V, $\text{R}_{\text{L}}$ = 50 $\Omega,V_{\text{LE}}$ = $V_{\text{DD}},\text{C}_{\text{L}}$ = 100 pF		9.5		ns
T <sub>SELOFF</sub>	SEL to Switch turn OFF time	$V_{IS}$ = 1 V, $R_L$ = 50 $\Omega$ , $V_{LE}$ = $V_{DD}$ , $C_L$ = 100pF		5		ns
T <sub>SET</sub>	LE setup time SEL to LE	$V_{\text{IS}}$ = 1 V, $R_{\text{L}}$ = 50 $\Omega,V_{\text{LE}}$ = $V_{\text{DD}},C_{\text{L}}$ = 100 pF		1		ns
T <sub>HOLD</sub>	LE hold time LE to SEL	$V_{IS}$ = 1 V, $R_L$ = 50 $\Omega,V_{LE}$ = $V_{DD},C_L$ = 100 pF		1		ns

### **TYPICAL OPERATING CHARACTERISTICS**

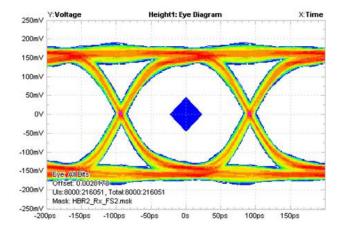


Figure 4. Reference DisplayPort 1.2 Eye Diagram without Switch at 5.4 Gbps, 340 mV<sub>pp</sub> Differential Swing

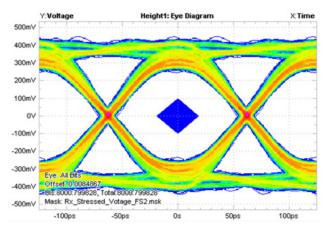


Figure 6. Reference PCle 3.0 Eye Diagram without Switch at 8 Gbps, 800 mV\_{pp} Differential Swing

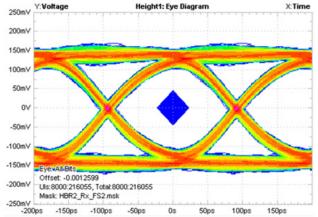


Figure 5. DisplayPort 1.2 Eye Diagram through NCN3612B at 5.4 Gbps, 340 mV<sub>pp</sub> Differential Swing

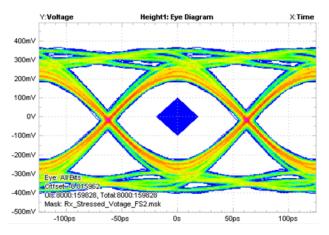
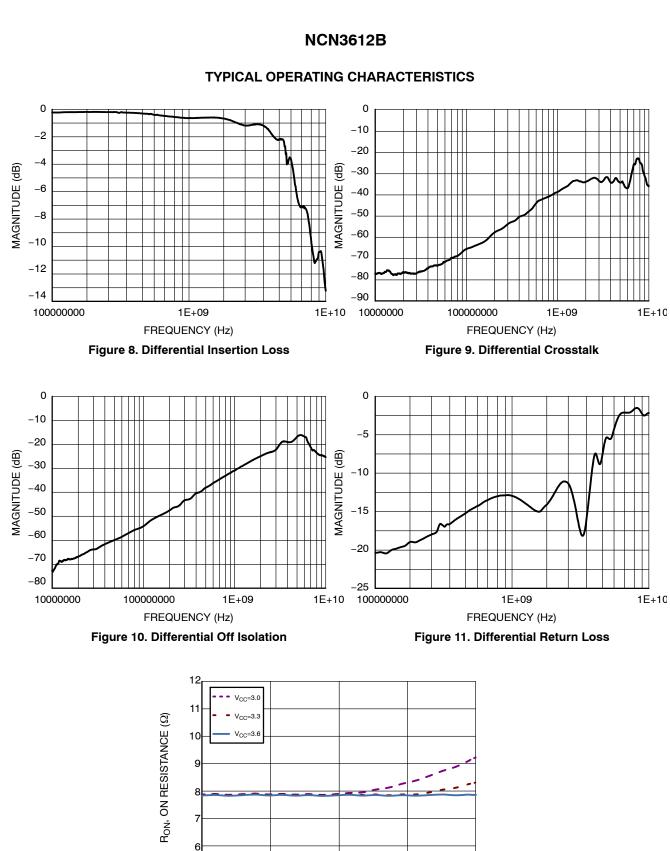


Figure 7. PCIe 3.0 Eye Diagram through NCN3612B at 8 Gbps, 800 mV<sub>pp</sub> Differential Swing



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V<sub>IS</sub> (V) Figure 12. R<sub>ON</sub> vs. V<sub>IS</sub>

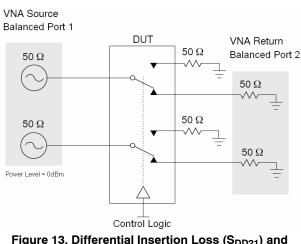
1.5

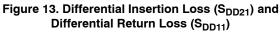
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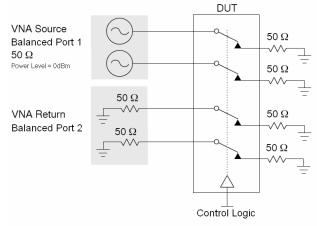
5L 0

0.5

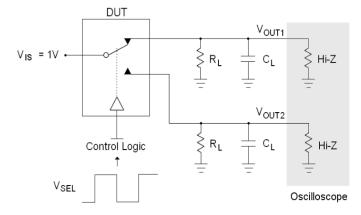
### PARAMETER MEASUREMENT INFORMATION

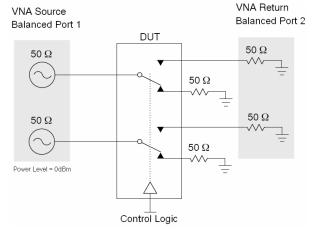




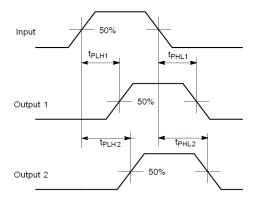




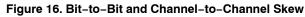


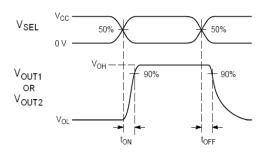






 $t_{skew} = |t_{PLH1} - t_{PLH2}| \text{ or } |t_{PHL1} - t_{PHL2}|$ 





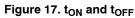
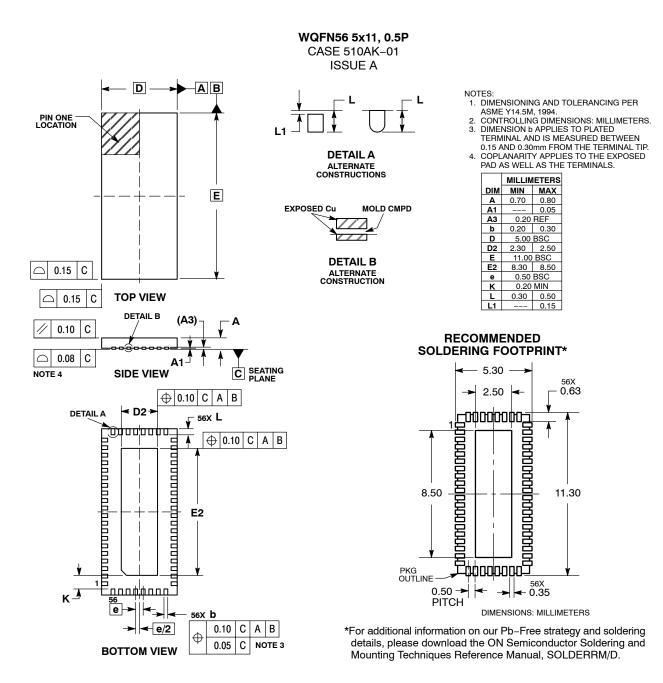




Figure 18. Off State Leakage



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